



# AiP74LV04 Hex Inverter

## Product Specification

### Specification Revision History:

| Version    | Date    | Description   |
|------------|---------|---|
| 2017-05-A1 | 2017-05 | New   |
| 2021-12-A2 | 2021-12 | Modify Ordering Information   |
| 2022-02-A3 | 2022-02 | Modify ambient temperature to $-40^{\circ}\text{C}\sim+105^{\circ}\text{C}$ and add electrical characteristics of $-40^{\circ}\text{C}\sim+105^{\circ}\text{C}$ |
|            |         |   |



## 1、 General Description

The AiP74LV04 is a low-voltage Si-gate CMOS device that is pin and function compatible with AiP74HC04 and AiP74HCT04.

The AiP74LV04 provides six inverting buffers.

### Features:

- Wide operating voltage: 1.0V to 5.5V
- Optimized for low voltage applications: 1.0V to 3.6V
- Accepts TTL input levels between  $V_{CC}=2.7V$  and  $V_{CC}=3.6V$
- Typical output ground bounce  $< 0.8V$  at  $V_{CC}=3.3V$  and  $T_{amb}=25^{\circ}C$
- Typical HIGH-level output voltage ( $V_{OH}$ ) undershoot:  $>2V$  at  $V_{CC}=3.3V$  and  $T_{amb}=25^{\circ}C$
- Specified from  $-40^{\circ}C$  to  $+105^{\circ}C$
- Packaging information: DIP14/SOP14/TSSOP14

**Ordering Information:****Tube packing specifications:**

| Part number      | Packaging form | Marking code | Tube quantity  | Boxed tube quantity | Boxed quantity   | Notes  |
|------------------|----------------|--------------|----------------|---------------------|------------------|--|
| AiP74LV04DA14.TB | DIP14          | 74LV04       | 25<br>PCS/tube | 40<br>tube/box      | 1000<br>PCS/box  | Dimensions of plastic enclosure:<br>19.0mm×6.4mm<br>Pin spacing:<br>2.54mm |
| AiP74LV04SA14.TB | SOP14          | 74LV04       | 50<br>PCS/tube | 200<br>tube/box     | 10000<br>PCS/box | Dimensions of plastic enclosure:<br>8.7mm×3.9mm<br>Pin spacing:<br>1.27mm  |
| AiP74LV04TA14.TB | TSSOP14        | 74LV04       | 94<br>PCS/tube | 200<br>tube/box     | 18800<br>PCS/box | Dimensions of plastic enclosure:<br>5.0mm×4.4mm<br>Pin spacing:<br>0.65mm  |

**Reel packing specifications:**

| Part number      | Packaging form | Marking code | Reel quantity    | Boxed reel quantity | Notes   |
|------------------|----------------|--------------|------------------|---------------------|---|
| AiP74LV04SA14.TR | SOP14          | 74LV04       | 4000<br>PCS/reel | 8000<br>PCS/box     | Dimensions of plastic enclosure:<br>8.7mm×3.9mm<br>Pin spacing:<br>1.27mm |
| AiP74LV04TA14.TR | TSSOP14        | 74LV04       | 5000<br>PCS/reel | 10000<br>PCS/box    | Dimensions of plastic enclosure:<br>5.0mm×4.4mm<br>Pin spacing:<br>0.65mm |

Note: If the physical information is inconsistent with the ordering information, please refer to the actual product.



## 2、Block Diagram And Pin Description

### 2.1、Block Diagram

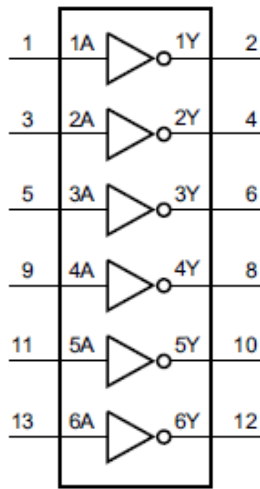


Figure 1. Logic symbol

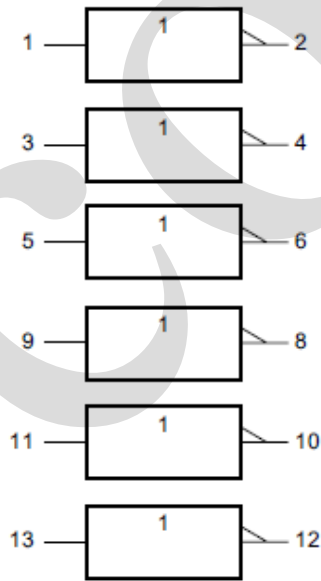


Figure 2. IEC logic symbol

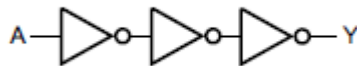
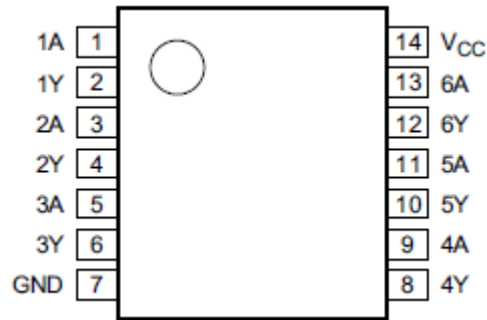


Figure 3. Logic diagram (one gate)



## 2.2、Pin Configurations



## 2.3、Pin Description

| Pin No. | Pin Name        | Description    |
|---------|-----------------|----------------|
| 1       | 1A              | data input     |
| 2       | 1Y              | data output    |
| 3       | 2A              | data input     |
| 4       | 2Y              | data output    |
| 5       | 3A              | data input     |
| 6       | 3Y              | data output    |
| 7       | GND             | ground (0V)    |
| 8       | 4Y              | data output    |
| 9       | 4A              | data input     |
| 10      | 5Y              | data output    |
| 11      | 5A              | data input     |
| 12      | 6Y              | data output    |
| 13      | 6A              | data input     |
| 14      | V <sub>CC</sub> | supply voltage |

## 2.4、Function Table

| Input | Output |
|-------|--------|
| nA    | nY     |
| L     | H      |
| H     | L      |

Note: H=HIGH voltage level; L=LOW voltage level.



## 3、Electrical Parameter

### 3.1、Absolute Maximum Ratings

(Voltages are referenced to GND(ground=0V), unless otherwise specified.)

| Parameter               | Symbol    | Conditions                           | Min. | Max.     | Unit |
|-------------------------|-----------|--------------------------------------|------|----------|------|
| supply voltage          | $V_{CC}$  | -                                    | -0.5 | +7.0     | V    |
| input clamping current  | $I_{IK}$  | $V_I < -0.5V$ or $V_I > V_{CC}+0.5V$ | -    | $\pm 20$ | mA   |
| output clamping current | $I_{OK}$  | $V_O < -0.5V$ or $V_O > V_{CC}+0.5V$ | -    | $\pm 50$ | mA   |
| output current          | $I_O$     | $V_O = -0.5V$ to $(V_{CC}+0.5V)$     | -    | $\pm 25$ | mA   |
| supply current          | $I_{CC}$  | -                                    | -    | 50       | mA   |
| ground current          | $I_{GND}$ | -                                    | -50  | -        | mA   |
| storage temperature     | $T_{stg}$ | -                                    | -65  | +150     | °C   |
| total power dissipation | $P_{tot}$ | -                                    | -    | 500      | mW   |
| Soldering temperature   | $T_L$     | 10s                                  | DIP  | 245      | °C   |
|                         |           |                                      | SOP  | 250      | °C   |

Note:

- [1] For DIP14 packages: above 70°C the value of  $P_{tot}$  derates linearly with 12mW/K.
- [2] For SOP14 packages: above 70°C the value of  $P_{tot}$  derates linearly with 8mW/K.
- [3] For (T)SSOP14 packages: above 60°C the value of  $P_{tot}$  derates linearly with 5.5mW/K.

### 3.2、Recommended Operating Conditions

| Parameter                           | Symbol              | Conditions              | Min. | Typ. | Max.     | Unit |
|-------------------------------------|---------------------|-------------------------|------|------|----------|------|
| supply voltage                      | $V_{CC}$            | -                       | 1.0  | 3.3  | 5.5      | V    |
| input voltage                       | $V_I$               | -                       | 0    | -    | $V_{CC}$ | V    |
| output voltage                      | $V_O$               | -                       | 0    | -    | $V_{CC}$ | V    |
| ambient temperature                 | $T_{amb}$           | -                       | -40  | -    | +105     | °C   |
| input transition rise and fall rate | $\Delta t/\Delta V$ | $V_{CC}=1.0V$ to $2.0V$ | -    | -    | 500      | ns/V |
|                                     |                     | $V_{CC}=2.0V$ to $2.7V$ | -    | -    | 200      | ns/V |
|                                     |                     | $V_{CC}=2.7V$ to $3.6V$ | -    | -    | 100      | ns/V |
|                                     |                     | $V_{CC}=3.6V$ to $5.5V$ | -    | -    | 50       | ns/V |

Note: The static characteristics are guaranteed from  $V_{CC}=1.2V$  to  $V_{CC}=5.5V$ , but LV devices are guaranteed to function down to  $V_{CC}=1.0V$  (with input levels GND or  $V_{CC}$ ).



### 3.3、Electrical Characteristics

#### 3.3.1、DC Characteristics 1

( $T_{amb} = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ , voltages are referenced to GND (ground=0V), unless otherwise specified.)

| Parameter                 | Symbol          | Conditions   | Min.  | Typ. | Max.                | Unit          |   |
|---------------------------|-----------------|--|---|------|---------------------|---------------|---|
| HIGH-level input voltage  | $V_{IH}$        | $V_{CC}=1.2\text{V}$   | 0.9   | -    | -                   | V             |   |
|                           |                 | $V_{CC}=2.0\text{V}$   | 1.4   | -    | -                   | V             |   |
|                           |                 | $V_{CC}=2.7\text{V}$ to $3.6\text{V}$  | 2.0   | -    | -                   | V             |   |
|                           |                 | $V_{CC}=4.5\text{V}$ to $5.5\text{V}$  | $0.7 \times V_{CC}$                           | -    | -                   | V             |   |
| LOW-level input voltage   | $V_{IL}$        | $V_{CC}=1.2\text{V}$   | -   | -    | 0.3                 | V             |   |
|                           |                 | $V_{CC}=2.0\text{V}$   | -   | -    | 0.6                 | V             |   |
|                           |                 | $V_{CC}=2.7\text{V}$ to $3.6\text{V}$  | -   | -    | 0.8                 | V             |   |
|                           |                 | $V_{CC}=4.5\text{V}$ to $5.5\text{V}$  | -   | -    | $0.3 \times V_{CC}$ | V             |   |
| HIGH-level output voltage | $V_{OH}$        | $V_I = V_{IH}$ or $V_{IL}$   | $I_O = -100\mu\text{A}; V_{CC} = 1.2\text{V}$ | -    | 1.2                 | -             | V |
|                           |                 |  | $I_O = -100\mu\text{A}; V_{CC} = 2.0\text{V}$ | 1.8  | 2.0                 | -             | V |
|                           |                 |  | $I_O = -100\mu\text{A}; V_{CC} = 2.7\text{V}$ | 2.5  | 2.7                 | -             | V |
|                           |                 |  | $I_O = -100\mu\text{A}; V_{CC} = 3.0\text{V}$ | 2.8  | 3.0                 | -             | V |
|                           |                 |  | $I_O = -100\mu\text{A}; V_{CC} = 4.5\text{V}$ | 4.3  | 4.5                 | -             | V |
|                           |                 |  | $I_O = -6\text{mA}; V_{CC} = 3.0\text{V}$     | 2.4  | 2.82                | -             | V |
|                           |                 |  | $I_O = -12\text{mA}; V_{CC} = 4.5\text{V}$    | 3.6  | 4.2                 | -             | V |
| LOW-level output voltage  | $V_{OL}$        | $V_I = V_{IH}$ or $V_{IL}$   | $I_O = 100\mu\text{A}; V_{CC} = 1.2\text{V}$  | -    | 0                   | -             | V |
|                           |                 |  | $I_O = 100\mu\text{A}; V_{CC} = 2.0\text{V}$  | -    | 0                   | 0.2           | V |
|                           |                 |  | $I_O = 100\mu\text{A}; V_{CC} = 2.7\text{V}$  | -    | 0                   | 0.2           | V |
|                           |                 |  | $I_O = 100\mu\text{A}; V_{CC} = 3.0\text{V}$  | -    | 0                   | 0.2           | V |
|                           |                 |  | $I_O = 100\mu\text{A}; V_{CC} = 4.5\text{V}$  | -    | 0                   | 0.2           | V |
|                           |                 |  | $I_O = 6\text{mA}; V_{CC} = 3.0\text{V}$      | -    | 0.25                | 0.40          | V |
|                           |                 |  | $I_O = 12\text{mA}; V_{CC} = 4.5\text{V}$     | -    | 0.35                | 0.55          | V |
| input leakage current     | $I_I$           | $V_I = V_{CC}$ or GND;<br>$V_{CC} = 5.5\text{V}$                                     | -   | -    | 1.0                 | $\mu\text{A}$ |   |
| supply current            | $I_{CC}$        | $V_I = V_{CC}$ or GND; $I_O = 0\text{A}$ ;<br>$V_{CC} = 5.5\text{V}$                 | -   | -    | 20                  | $\mu\text{A}$ |   |
| additional supply current | $\Delta I_{CC}$ | per input; $V_I = V_{CC} - 0.6\text{V}$ ;<br>$V_{CC} = 2.7\text{V}$ to $3.6\text{V}$ | -   | -    | 500                 | $\mu\text{A}$ |   |
| input capacitance         | $C_I$           | -  | -   | 3.5  | -                   | pF            |   |

Note: All typical values are measured at  $T_{amb} = 25^{\circ}\text{C}$



### 3.3.2、DC Characteristics 2

( $T_{amb}=-40^{\circ}\text{C}$  to  $+105^{\circ}\text{C}$ , voltages are referenced to GND (ground=0V), unless otherwise specified.)

| Parameter                 | Symbol          | Conditions   | Min.                                      | Typ. | Max.                | Unit          |   |
|---------------------------|-----------------|--|---|------|---------------------|---------------|---|
| HIGH-level input voltage  | $V_{IH}$        | $V_{CC}=1.2\text{V}$   | 0.9                                       | -    | -                   | V             |   |
|                           |                 | $V_{CC}=2.0\text{V}$   | 1.4                                       | -    | -                   | V             |   |
|                           |                 | $V_{CC}=2.7\text{V}$ to $3.6\text{V}$  | 2.0                                       | -    | -                   | V             |   |
|                           |                 | $V_{CC}=4.5\text{V}$ to $5.5\text{V}$  | $0.7 \times V_{CC}$                       | -    | -                   | V             |   |
| LOW-level input voltage   | $V_{IL}$        | $V_{CC}=1.2\text{V}$   | -   | -    | 0.3                 | V             |   |
|                           |                 | $V_{CC}=2.0\text{V}$   | -   | -    | 0.6                 | V             |   |
|                           |                 | $V_{CC}=2.7\text{V}$ to $3.6\text{V}$  | -   | -    | 0.8                 | V             |   |
|                           |                 | $V_{CC}=4.5\text{V}$ to $5.5\text{V}$  | -   | -    | $0.3 \times V_{CC}$ | V             |   |
| HIGH-level output voltage | $V_{OH}$        | $V_I = V_{IH}$ or $V_{IL}$   | $I_O=-100\mu\text{A}; V_{CC}=2.0\text{V}$ | 1.8  | -                   | -             | V |
|                           |                 |  | $I_O=-100\mu\text{A}; V_{CC}=2.7\text{V}$ | 2.5  | -                   | -             | V |
|                           |                 |  | $I_O=-100\mu\text{A}; V_{CC}=3.0\text{V}$ | 2.8  | -                   | -             | V |
|                           |                 |  | $I_O=-100\mu\text{A}; V_{CC}=4.5\text{V}$ | 4.3  | -                   | -             | V |
|                           |                 |  | $I_O=-6\text{mA}; V_{CC}=3.0\text{V}$     | 2.2  | -                   | -             | V |
|                           |                 |  | $I_O=-12\text{mA}; V_{CC}=4.5\text{V}$    | 3.5  | -                   | -             | V |
| LOW-level output voltage  | $V_{OL}$        | $V_I = V_{IH}$ or $V_{IL}$   | $I_O=100\mu\text{A}; V_{CC}=1.2\text{V}$  | -    | -                   | 0.2           | V |
|                           |                 |  | $I_O=100\mu\text{A}; V_{CC}=2.0\text{V}$  | -    | -                   | 0.2           | V |
|                           |                 |  | $I_O=100\mu\text{A}; V_{CC}=2.7\text{V}$  | -    | -                   | 0.2           | V |
|                           |                 |  | $I_O=100\mu\text{A}; V_{CC}=3.0\text{V}$  | -    | -                   | 0.2           | V |
|                           |                 |  | $I_O=100\mu\text{A}; V_{CC}=4.5\text{V}$  | -    | -                   | 0.50          | V |
|                           |                 |  | $I_O=6\text{mA}; V_{CC}=3.0\text{V}$      | -    | -                   | 0.65          | V |
| input leakage current     | $I_I$           | $V_I=V_{CC}$ or GND;<br>$V_{CC}=5.5\text{V}$                                   | -   | -    | 1.0                 | $\mu\text{A}$ |   |
| supply current            | $I_{CC}$        | $V_I=V_{CC}$ or GND; $I_O=0\text{A}$ ;<br>$V_{CC}=5.5\text{V}$                 | -   | -    | 40                  | $\mu\text{A}$ |   |
| additional supply current | $\Delta I_{CC}$ | per input; $V_I=V_{CC}-0.6\text{V}$ ;<br>$V_{CC}=2.7\text{V}$ to $3.6\text{V}$ | -   | -    | 850                 | $\mu\text{A}$ |   |

Note: All typical values are measured at  $T_{amb}=25^{\circ}\text{C}$





### 3.3.3、AC Characteristics 1

( $T_{amb}=-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ , voltages are referenced to GND (ground=0V), unless otherwise specified.)

| Parameter                           | Symbol   | Conditions  | Min.   | Typ. | Max. | Unit |    |
|-------------------------------------|----------|---|--|------|------|------|----|
| nA to nY;<br>propagation<br>delay   | $t_{pd}$ | see Figure 5  | $V_{CC}=1.2\text{V}$   | -    | 40   | -    | ns |
|                                     |          |   | $V_{CC}=2.0\text{V}$   | -    | 14   | 20   | ns |
|                                     |          |   | $V_{CC}=2.7\text{V}$   | -    | 10   | 15   | ns |
|                                     |          |   | $V_{CC}=3.0\text{V}$ to $3.6\text{V}$ ;<br>$C_L=15\text{pF}$ | -    | 6    | -    | ns |
|                                     |          |   | $V_{CC}=3.0\text{V}$ to $3.6\text{V}$                        | -    | 8    | 12   | ns |
|                                     |          | $V_{CC}=4.5\text{V}$ to $5.5\text{V}$                                   | -  | -    | 9    | ns   |    |
| Power<br>dissipation<br>capacitance | $C_{PD}$ | $C_L=50\text{pF}$ ; $f_i=1\text{MHz}$ ;<br>$V_i=\text{GND}$ to $V_{CC}$ | -  | 21   | -    | pF   |    |

Note:

[1] Typical values are measured at  $T_{amb}=25^{\circ}\text{C}$ .

[2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[3] Typical values are measured at nominal supply voltage ( $V_{CC}=3.3\text{V}$ ).

[4]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in uW).

$$P_D=(C_{PD}\times V_{CC}^2\times f_i\times N)+\sum(C_L\times V_{CC}^2\times f_o)$$
 where:

$f_i$ =input frequency in MHz;

$f_o$ =output frequency in MHz;

$C_L$ =output load capacitance in pF;

$V_{CC}$ =supply voltage in V;

$N$ =number of inputs switching;

$\sum(C_L\times V_{CC}^2\times f_o)$ =sum of outputs.

### 3.3.4、AC Characteristics 2

( $T_{amb}=-40^{\circ}\text{C}$  to  $+105^{\circ}\text{C}$ , voltages are referenced to GND (ground=0V), unless otherwise specified.)

| Parameter                         | Symbol   | Conditions   | Min.                                  | Typ. | Max. | Unit |    |
|-----------------------------------|----------|--------------|---------------------------------------|------|------|------|----|
| nA to nY;<br>propagation<br>delay | $t_{pd}$ | see Figure 5 | $V_{CC}=2.0\text{V}$                  | -    | -    | 25   | ns |
|                                   |          |              | $V_{CC}=2.7\text{V}$                  | -    | -    | 19   | ns |
|                                   |          |              | $V_{CC}=3.0\text{V}$ to $3.6\text{V}$ | -    | -    | 15   | ns |
|                                   |          |              | $V_{CC}=4.5\text{V}$ to $5.5\text{V}$ | -    | -    | 11   | ns |

Note:

[1] Typical values are measured at  $T_{amb}=25^{\circ}\text{C}$ .

[2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[3] Typical values are measured at nominal supply voltage ( $V_{CC}=3.3\text{V}$ ).



## 4、Testing Circuit

### 4.1、AC Testing Circuit

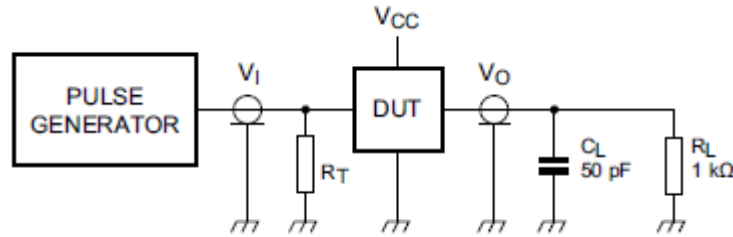


Figure 4. Test circuit for measuring switching times

Definitions for test circuit:

$R_L$ =Load resistance.

$C_L$ =Load capacitance including jig and probe capacitance.

$R_T$ =Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

### 4.2、AC Testing Waveforms

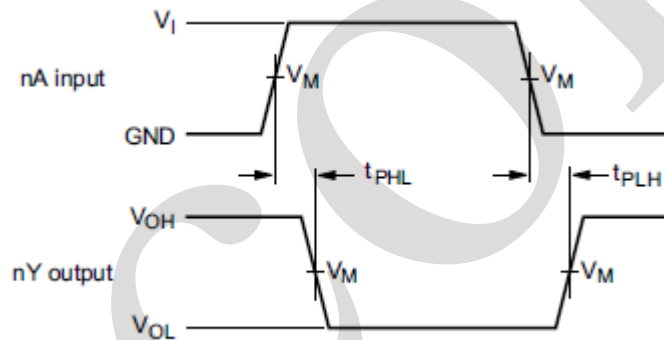


Figure 5. The input (nA) to output (nY) propagation delays

### 4.3、Measurement Points

| Supply voltage | Input               | Output              |
|----------------|---------------------|---------------------|
| $V_{CC}$       | $V_M$               | $V_M$               |
| <2.7V          | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ |
| 2.7V to 3.6V   | 1.5V                | 1.5V                |
| $\geq 4.5V$    | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ |

### 4.4、Test Data

| Supply voltage | Input    |              |
|----------------|----------|--------------|
| $V_{CC}$       | $V_I$    | $t_r, t_f$   |
| <2.7V          | $V_{CC}$ | $\leq 2.5ns$ |
| 2.7V to 3.6V   | 2.7V     | $\leq 2.5ns$ |
| $\geq 4.5V$    | $V_{CC}$ | $\leq 2.5ns$ |

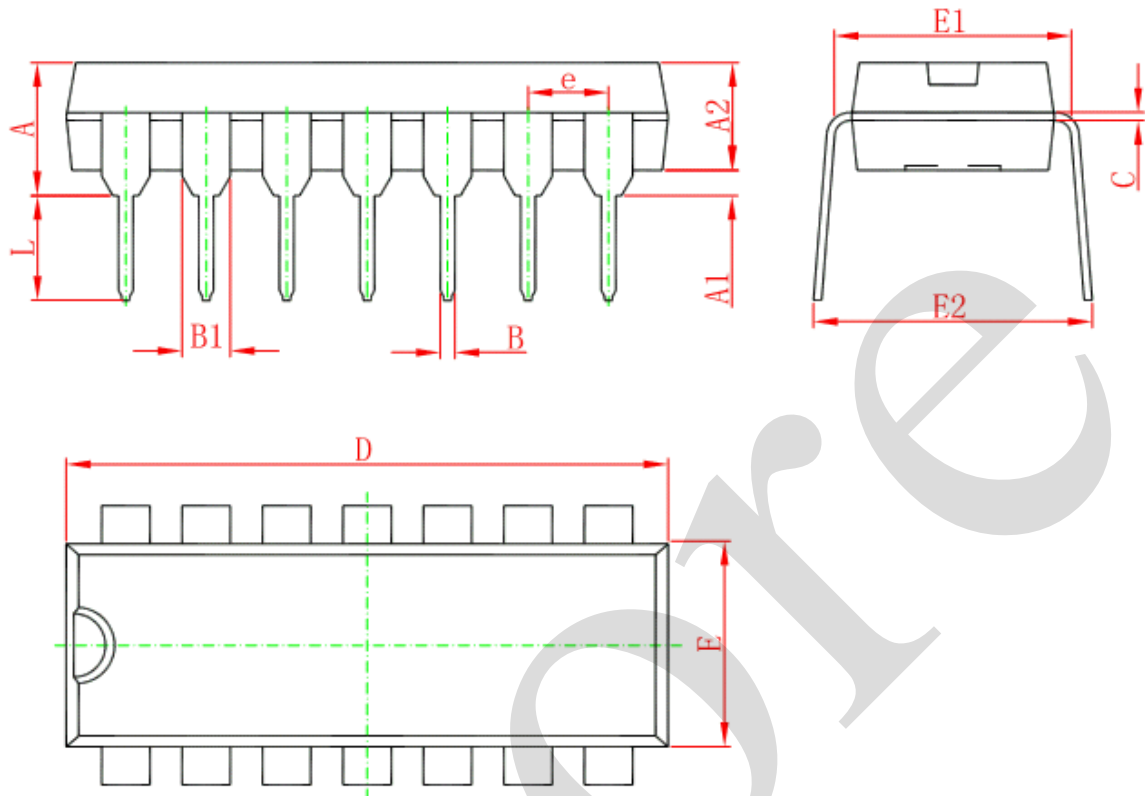


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## 5、Package Information

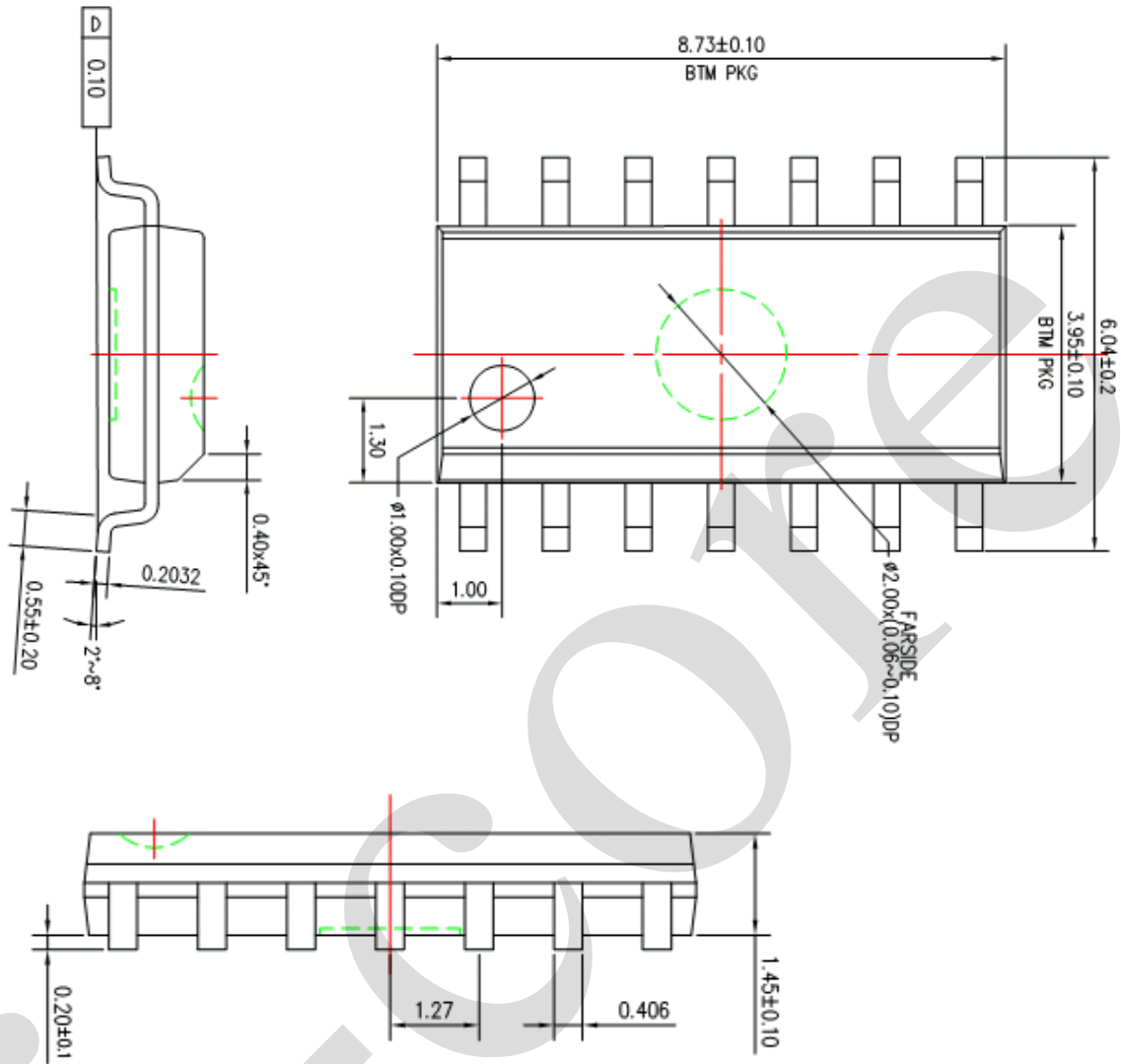
### 5.1、DIP14



| Symbol | Dimensions In Millimeters |        | Dimensions In Inches |       |
|--------|---------------------------|--------|----------------------|-------|
|        | Min                       | Max    | Min                  | Max   |
| A      | 3.710                     | 4.310  | 0.146                | 0.170 |
| A1     | 0.510                     |        | 0.020                |       |
| A2     | 3.200                     | 3.600  | 0.126                | 0.142 |
| B      | 0.380                     | 0.570  | 0.015                | 0.022 |
| B1     | 1.524 (BSC)               |        | 0.060 (BSC)          |       |
| C      | 0.204                     | 0.360  | 0.008                | 0.014 |
| D      | 18.800                    | 19.200 | 0.740                | 0.756 |
| E      | 6.200                     | 6.600  | 0.244                | 0.260 |
| E1     | 7.320                     | 7.920  | 0.288                | 0.312 |
| e      | 2.540 (BSC)               |        | 0.100 (BSC)          |       |
| L      | 3.000                     | 3.600  | 0.118                | 0.142 |
| E2     | 8.400                     | 9.000  | 0.331                | 0.354 |

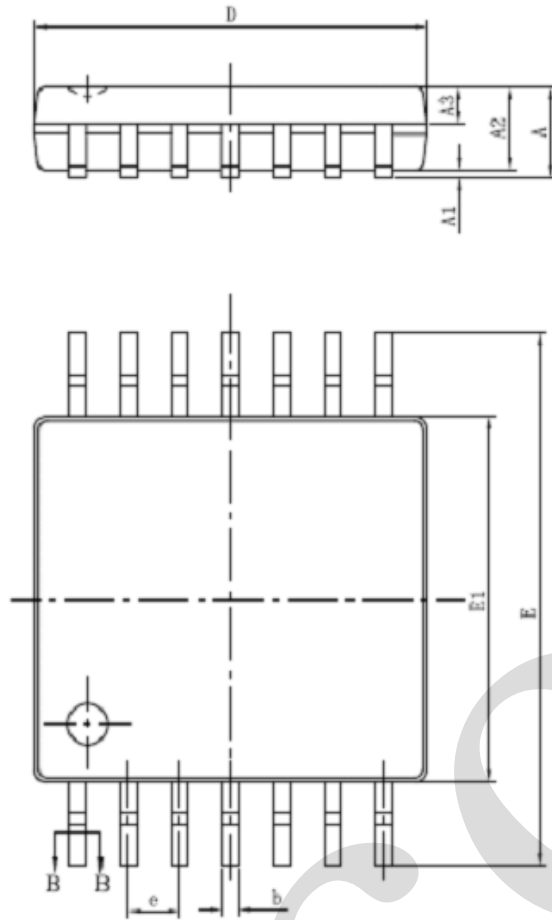


5.2、SOP14

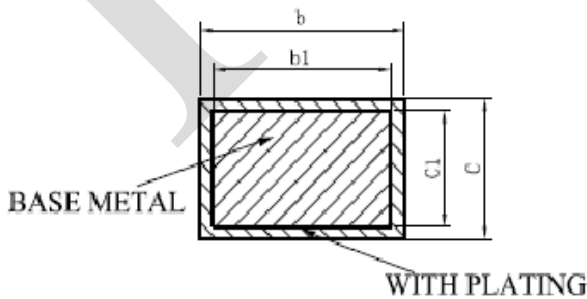
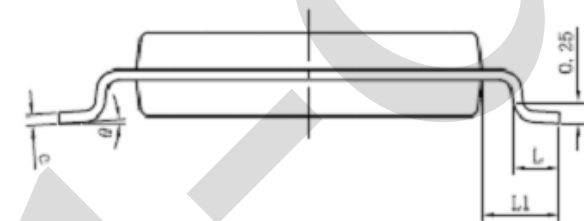




## 5.3、TSSOP14



| SYMBOL   | MILLIMETER |      |
|----------|------------|------|
|          | MIN        | MAX  |
| A        | —          | 1.20 |
| A1       | 0.05       | 0.15 |
| A2       | 0.90       | 1.05 |
| A3       | 0.39       | 0.49 |
| b        | 0.20       | 0.30 |
| b1       | 0.19       | 0.25 |
| c        | 0.13       | 0.19 |
| c1       | 0.12       | 0.14 |
| D        | 4.86       | 5.06 |
| E1       | 4.30       | 4.50 |
| E        | 6.20       | 6.60 |
| e        | 0.65BSC    |      |
| L        | 0.45       | 0.75 |
| L1       | 1.00BSC    |      |
| $\theta$ | 0          | 8°   |



SECTION B-B



## 6、 Statements And Notes

### 6.1、 The name and content of Hazardous substances or Elements in the product

| Part name               | Hazardous substances or Elements  |                               |                               |                               |                          |                                |                   |                       |                           |                      |
|-------------------------|---|-------------------------------|-------------------------------|-------------------------------|--------------------------|--------------------------------|-------------------|-----------------------|---------------------------|----------------------|
|                         | Lead and lead compounds   | Mercury and mercury compounds | Cadmium and cadmium compounds | Hexavalent chromium compounds | Polybrominated biphenyls | Polybrominated biphenyl ethers | Dibutyl phthalate | Butylbenzyl phthalate | Di-2-ethylhexyl phthalate | Diisobutyl phthalate |
| Lead frame              | ○   | ○                             | ○                             | ○                             | ○                        | ○                              | ○                 | ○                     | ○                         | ○                    |
| Plastic resin           | ○   | ○                             | ○                             | ○                             | ○                        | ○                              | ○                 | ○                     | ○                         | ○                    |
| Chip                    | ○   | ○                             | ○                             | ○                             | ○                        | ○                              | ○                 | ○                     | ○                         | ○                    |
| The lead                | ○   | ○                             | ○                             | ○                             | ○                        | ○                              | ○                 | ○                     | ○                         | ○                    |
| Plastic sheet installed | ○   | ○                             | ○                             | ○                             | ○                        | ○                              | ○                 | ○                     | ○                         | ○                    |
| explanation             | ○: Indicates that the content of hazardous substances or elements in the detection limit of the following the SJ/T11363-2006 standard.<br>×: Indicates that the content of hazardous substances or elements exceeding the SJ/T11363-2006 Standard limit requirements. |                               |                               |                               |                          |                                |                   |                       |                           |                      |

### 6.2、 Notion

Recommended carefully reading this information before the use of this product;

The information in this document are subject to change without notice;

This information is using to the reference only, the company is not responsible for any loss;

The company is not responsible for the any infringement of the third party patents or other rights of the responsibility.